Thermoelectric properties of CH$_3$NH$_3$PbI$_3$
investigated using density functional theory and
Boltzmann transport calculations

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Abstract. Mixed organometal perovskite CH$_3$NH$_3$PbI$_3$ has recently emerged as a promising
candidate for low cost, high-efficiency solar cells. The materials thermoelectric properties which
are key to the solar thermoelectric applications have not been investigated extensively. In this
paper, the thermoelectric properties of organic-inorganic halide perovskite CH$_3$NH$_3$PbI$_3$ were
studied by solving the semiclassical Boltzmann transport equation on top of density functional
theory calculations using maximally-localised Wannier functions (MLWFs). Electronic
transport properties were evaluated within the constant relaxation time approximation at four
different temperatures 300 K, 500 K, 700 K, and 900 K. The electrical conductivity ($\sigma$) was
found to be almost constant in the investigated temperature range, while the Seebeck coefficient
($S$) was found to decrease with increasing temperature and the electronic thermal conductivity
($\kappa_e$) was found to increase with increasing temperature. Theoretical results for the power factor
($S^2\sigma$) and the figure of merit ($ZT$) are analysed. The highest predicted average figure of merit
is found to be over 0.8 at 900 K.

1. Introduction
Organic-inorganic perovskites ABI$_3$ (A = CH$_3$NH$_3$ or NH$_2$CHNH$_2$; B = Sn, Pb), have been
specified as light harvesting materials [1]. In addition, they were treated as new thermoelectric
materials with a large Seebeck coefficient and low thermal conductivity [2, 3], bring to light that
these materials might be potential candidates for thermoelectric applications [4]. The efficiency
of thermoelectric devices is characterized by a dimensionless figure of merit $ZT = S^2\sigma T/\kappa$, where
$S$, $\sigma$, $T$ and $\kappa$ refer to Seebeck coefficient, electrical conductivity, temperature and total thermal
conductivity, respectively [5]. Both phonons and electrons are heat carriers, therefore the
total thermal conductivity has two contributions, the lattice thermal conductivity component
$\kappa_l$ and the electronic thermal conductivity component $\kappa_e$. Thermoelectric materials with a large
thermoelectric figure of merit ($ZT$) can convert heat to electricity via the Seebeck effect. To
have a large figure of merit one needs a large power factor $S^2\sigma$ and low thermal conductivity
$\kappa$. In the present work, we studied the thermoelectric properties of the CH$_3$NH$_3$PbI$_3$ in an
orthorhombic system from a combination of semiclassical Boltzmann transport equation and density functional theory calculations using maximally-localised Wannier functions (MLWFs). Section 2 describes the methodology used in the investigation. Section 3 presents the results and discussion. Finally, we shall give our conclusion in section 4.

2. Methodology
In this work, the investigation of the electronic structure properties was performed using the Vienna Ab-initio Simulation Package (VASP) [6, 7] based on Density Functional Theory (DFT) [8, 9]. The Projector-Augmented Wave (PAW) [10] method was employed to treat electron-ion interactions. To describe the electrons exchange and correlation effects, we used the Generalized Gradient Approximation (GGA) as parameterized and revised by Perdew, Burke and Ernzerhof (PBEsol)[11]. 4 × 4 × 2 Monkhorst-Pack meshes were used in sampling the Brillouin zone with an energy cut-off of 520 eV. The atomic positions were fully optimized until all components of the forces were less than 1 meV/atom.

The thermoelectric and electronic transport properties were calculated by solving the semiclassical Boltzmann transport equations in the constant relaxation-time approximation (here $\tau = 10^{-14}$ s ) as implemented in the BoltzWann code [12]. The code uses a maximally-localized Wannier functions (MLWFs) [13] basis set to interpolate the bandstructure obtained from the above-mentioned DFT calculations. After using a $6 \times 4 \times 4$ k-points for the construction of the MLWFs, a $40 \times 40 \times 40$ was utilized to calculate the electronic transport properties such as Seebeck coefficient $S$, electrical conductivity $\sigma$, electronic thermal conductivity $\kappa_e$ and the power factor $S^2\sigma$. The computation of MLWFs has been performed within WANNIER90 package [14].

3. Results and discussion
3.1. Bandstructure and density of states
CH$_3$NH$_3$PbI$_3$ is orthorhombic at low temperature (space group Pnma, 62), with the unit cell shown in Figure 1. The bandstructure of the structurally optimized CH$_3$NH$_3$PbI$_3$ was calculated along the high symmetry points of the Brillouin zone (BZ) using the generalized gradient approximation (GGA) for solids (PBEsol). Figure 2 shows the bandstructure obtained from density functional theory (DFT) calculations. The Wannier functions interpolated bandstructure showed excellent agreement with previous first-principles results. The calculated band gap according to PBEsol without including spin orbit coupling was found to be 1.57 eV in good agreement with the experimental results of 1.61 eV [15] and with other theoretical predictions [16, 17]. The total density of states (DOS) and the projected DOS plots calculated for CH$_3$NH$_3$PbI$_3$ are presented in Figure 2.

Figure 1. (Color online) The crystal structure of orthorhombic CH$_3$NH$_3$PbI$_3$ (left) and its corresponding Brillouin zone (right). Filled red circles are the high symmetry points, while the red bold lines indicate segments of the high symmetry path ($\Gamma - X - S - Y - \Gamma$).
3.2. Thermoelectric properties

The calculated properties are plotted in Figures 3-7 as functions of the chemical potential $\mu$ at four different temperatures 300 K, 500 K, 700 K and 900 K.

The Seebeck coefficient $S$, is defined as the ratio of the electric field to the temperature gradient when the electrical current is zero. The calculated Seebeck coefficients as a function of chemical potential $\mu$ at different temperatures are presented in Figure 3. From Figure 3 it is clear that Seebeck coefficient of CH$_3$NH$_3$PbI$_3$ has positive values at chemical potential $\mu = 0$, indicating that it is a p-type semiconductor. In the $z$-direction the maximum values of $S$ were found to be (2535, 1484, 1062 and 899) $\mu$ VK$^{-1}$ at 300 K, 500 K, 700 K and 900 K respectively, which shows that this compound is a good candidate for thermoelectric applications. The absolute value of Seebeck coefficient was found to decrease with increasing temperature.

The calculated electrical conductivity $\sigma$ as a function of chemical potential at different temperatures are presented in Figure 4. Electrical conductivity was found to be almost temperature independent in the considered temperature range. This trend was observed in SnSe[18] and ScRhTe [19]. In general, the value of electrical conductivity increases with increase in absolute value of the chemical potential at all temperatures with the highest value $4.58 \times 10^6$ $\Omega^{-1}m^{-1}$ in the $z$-direction at chemical potential 2.84 eV.

The electronic thermal conductivity $\kappa_e$ as a function of chemical potential at different temperatures is plotted in Figure 5. At chemical potential 2.84 eV the maxima of the electronic thermal conductivity in $z$-direction increases from 33.6 Wm$^{-1}$K$^{-1}$ at 300 K to 95.68 Wm$^{-1}$K$^{-1}$ at 900 K.
Figure 4. (Color online) Variation of electrical conductivity with respect to chemical potential at different temperatures in the (a) $x$-direction, (b) $y$-direction, and (c) $z$-direction.

Figure 5. (Color online) Electronic thermal conductivity as a function of chemical potential at different temperatures in the (a) $x$-direction, (b) $y$-direction, and (c) $z$-direction.

The power factor $S^2\sigma$ as a function of chemical potential at different temperatures is shown in Figure 6. The maximum calculated value of the power factor was found to be 0.013 Wm$^{-1}$K$^{-2}$ in $z$-direction at 900 K and chemical potential 1.78 eV.

Figure 6. (Color online) Calculated power factor as a function of chemical potential at different temperatures in the (a) $x$-direction, (b) $y$-direction, and (c) $z$-direction.

Finally, Figure 7 shows the figure of merit $ZT$ for CH$_3$NH$_3$PbI$_3$ compound at different temperatures in the $x$-, $y$-, and $z$-directions. Figure 7 shows that the maximum value of figure of merit was found to be over 0.8 at 900 K and chemical potential of 1.33 eV, which is a promising value for thermoelectric applications. Typical thermoelectric materials like Bi$_2$Te$_3$ ($ZT = 0.8$ at
Figure 7. (Color online) Calculated figure of merit as a function of chemical potential at different temperatures in the (a) \(x\)-direction, (b) \(y\)-direction, and (c) \(z\)-direction.

300 K) [20] and CsBi\(_4\)Te\(_6\) (\(ZT = 0.82\) at 225 K) [21, 22] exhibit their maximum \(ZT\) at 300 K and 225 K, respectively, whereas the maximum calculated figure of merit of CH\(_3\)NH\(_3\)PbI\(_3\) compound appears after 900 K bringing it in the family of PbTe-based middle temperature thermoelectric materials like Ti-doped PbTe (\(ZT_{zz} = 0.64\) at 900 K) and Bi-doped PbTe (\(ZT_{xx} = 0.30\) at 900 K) [23], which indicate that our material is optimized at high temperatures.

From the presented figures, it is evident that the obtained Seebeck coefficient (Figure 3) and figure of merit (Figure 7) are nearly isotropic; while the electrical conductivity (Figure 4), the electronic thermal conductivity (Figure 5), and the power factor (Figure 6) are highly anisotropic with their optimal values in the \(z\)-direction.

4. Conclusion
We have carried out a detailed theoretical study of the thermoelectric properties of CH\(_3\)NH\(_3\)PbI\(_3\) in an orthorhombic system for the first time based on density functional theory combined with the Boltzmann transport theory within the constant relaxation time approximation as implemented in BoltzWann code. Based on the results, we end up with the fact that the perovskite CH\(_3\)NH\(_3\)PbI\(_3\) can be a good candidate for thermoelectric applications.

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References